

October 2014

## **FDMS7580**

# N-Channel Power Trench<sup>®</sup> MOSFET 25 V, 7.5 m $\Omega$

#### **Features**

- Max  $r_{DS(on)} = 7.5 \text{ m}\Omega$  at  $V_{GS} = 10 \text{ V}$ ,  $I_D = 15 \text{ A}$
- Max  $r_{DS(on)}$  = 11.1 m $\Omega$  at  $V_{GS}$  = 4.5 V,  $I_D$  = 12 A
- $\blacksquare$  Advanced Package and Silicon combination for low  $r_{\text{DS}(\text{on})}$  and high efficiency
- Next generation enhanced body diode technology, engineered for soft recovery
- MSL1 robust package design
- 100% UIL tested
- RoHS Compliant

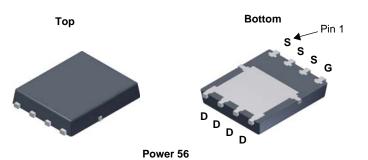


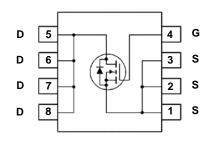
#### **General Description**

This N-Channel MOSFET has been designed specifically to improve the overall efficiency and to minimize switch node ringing of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low  $r_{DS(on)}$ , fast switching speed and body diode reverse recovery performance.

#### **Applications**

- Control MOSFET for Synchronous Buck Converters
- Notebook
- Server
- Telecomm
- High Efficiency DC-DC Switch Mode Power Supplies





### MOSFET Maximum Ratings T<sub>A</sub> = 25 °C unless otherwise noted

Symbol	Parameter		Ratings	Units	
V <sub>DS</sub>	Drain to Source Voltage			25	V
V <sub>GS</sub>	Gate to Source Voltage		(Note 4)	±20	V
I <sub>D</sub>	Drain Current -Continuous (Package limited)	T <sub>C</sub> = 25 °C		28	
	-Continuous (Silicon limited)	T <sub>C</sub> = 25 °C		49	^
	-Continuous	T <sub>A</sub> = 25 °C	(Note 1a)	15	A
	-Pulsed			60	
E <sub>AS</sub>	Single Pulse Avalanche Energy		(Note 3)	32	mJ
D	Power Dissipation	T <sub>C</sub> = 25 °C		27	W
$P_{D}$	Power Dissipation	T <sub>A</sub> = 25 °C	(Note 1a)	2.5	VV
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature R	ange		-55 to +150	°C

#### **Thermal Characteristics**

$R_{\thetaJC}$	Thermal Resistance, Junction to Case		4.6	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	50	C/VV

#### **Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS7580	FDMS7580	Power 56	13 "	12 mm	3000 units

## **Electrical Characteristics** T<sub>J</sub> = 25 °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	$I_D = 250 \mu A, V_{GS} = 0 V$	25			V
ΔBV <sub>DSS</sub> ΔΤ <sub>J</sub>	Breakdown Voltage Temperature Coefficient	I <sub>D</sub> = 250 μA, referenced to 25 °C		18		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V			1	μΑ
$I_{GSS}$	Gate to Source Leakage Current	V <sub>GS</sub> = 20 V, V <sub>DS</sub> = 0 V			100	nA

#### **On Characteristics**

V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	1.0	1.6	3.0	V
$\Delta V_{GS(th)} \Delta T_J$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D$ = 250 $\mu$ A, referenced to 25 °C		-6		mV/°C
		$V_{GS} = 10 \text{ V}, I_D = 15 \text{ A}$		5.9	7.5	
r <sub>DS(on)</sub>	20(011)	$V_{GS} = 4.5 \text{ V}, I_D = 12 \text{ A}$		8.3	11.1	mΩ
		$V_{GS} = 10 \text{ V}, I_D = 15 \text{ A}, T_J = 125 \text{ °C}$		8.3	10.6	
9 <sub>FS</sub>	Forward Transconductance	V <sub>DD</sub> = 5 V, I <sub>D</sub> = 15 A		63		S

#### **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance	V 43.V.V 0.V	894	1190	pF
		$V_{DS} = 13 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1  MHz	277	370	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	1 - 1 1011 12	53	80	pF
R <sub>a</sub>	Gate Resistance		1.1	2.2	Ω

## **Switching Characteristics**

t <sub>d(on)</sub>	Turn-On Delay Time		7.3	15	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 13 V, I <sub>D</sub> = 15 A,	2.4	10	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, R_{GEN} = 6 \Omega$	17	31	ns
t <sub>f</sub>	Fall Time		2.1	10	ns
0	Total Gate Charge	V <sub>GS</sub> = 0 V to 10 V	14	20	nC
$Q_{g(TOT)}$	Total Gate Charge	$V_{GS} = 0 \text{ V to } 4.5 \text{ V}$ $V_{DD} = 13 \text{ V}$	6.5	10	nC
$Q_{gs}$	Total Gate Charge	I <sub>D</sub> = 15 A	2.9		nC
$Q_{gd}$	Gate to Drain "Miller" Charge		1.6		nC

#### **Drain-Source Diode Characteristics**

V <sub>SD</sub> Source	Source to Drain Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{S} = 2 \text{ A}$	(Note 2)	0.73	1.1	\/
	Source to Drain Diode Forward voltage	$V_{GS} = 0 \text{ V}, I_{S} = 15 \text{ A}$	(Note 2)	0.85	1.2	]
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 15 A, di/dt = 100 A/μs		19	34	ns
Q <sub>rr</sub>	Reverse Recovery Charge			5.1	10	nC
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 15 A, di/dt = 300 A/μs		15	27	ns
Q <sub>rr</sub>	Reverse Recovery Charge			8.9	18	

#### NOTES

<sup>1.</sup> R<sub>0JA</sub> is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R<sub>0JC</sub> is guaranteed by design while R<sub>0CA</sub> is determined by the user's board design.



a. 50 °C/W when mounted on a 1 in² pad of 2 oz copper



b.125 °C/W when mounted on

- 2. Pulse Test: Pulse Width < 300  $\mu\text{s},$  Duty cycle < 2.0 %.
- 3.  $E_{AS}$  of 32 mJ is based on starting  $T_J$  = 25 °C, L = 1 mH,  $I_{AS}$  = 8 A,  $V_{DD}$  = 23 V,  $V_{GS}$  = 10 V. 100% test at L = 0.3 mH,  $I_{AS}$  = 12 A.
- 4. As an N-ch device, the negative Vgs rating is for low duty cycle pulse occurrence only. No continuous rating is implied.

## Typical Characteristics T<sub>J</sub> = 25 °C unless otherwise noted

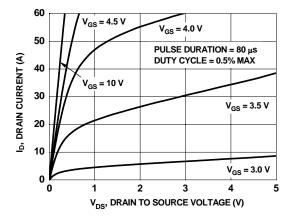


Figure 1. On-Region Characteristics

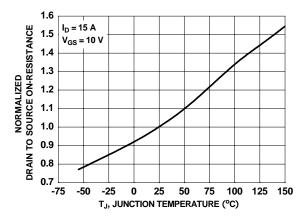


Figure 3. Normalized On-Resistance vs Junction Temperature

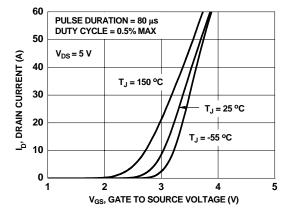


Figure 5. Transfer Characteristics

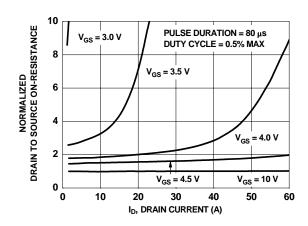


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

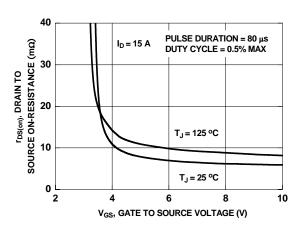


Figure 4. On-Resistance vs Gate to Source Voltage

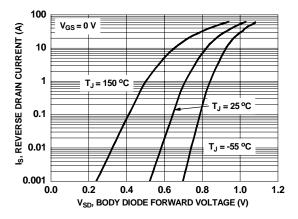


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

## **Typical Characteristics** $T_J = 25$ °C unless otherwise noted

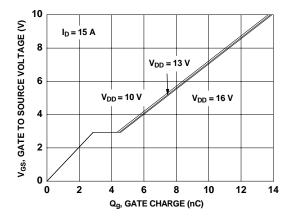


Figure 7. Gate Charge Characteristics

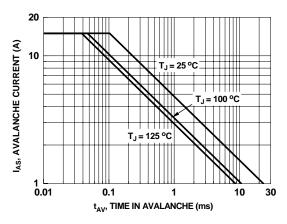


Figure 9. Unclamped Inductive Switching Capability

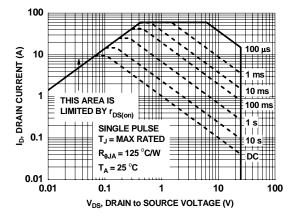


Figure 11. Forward Bias Safe Operating Area

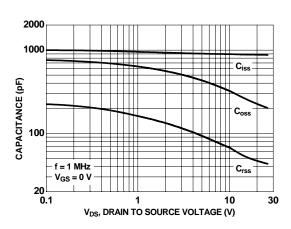


Figure 8. Capacitance vs Drain to Source Voltage

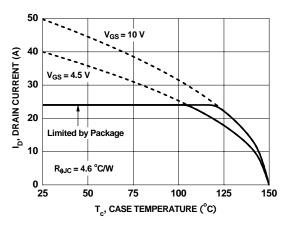


Figure 10. Maximum Continuous Drain Current vs Case Temperature

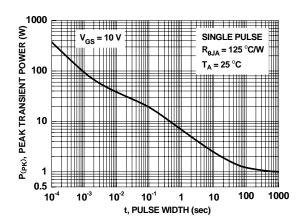


Figure 12. Single Pulse Maximum Power Dissipation

## **Typical Characteristics** $T_J = 25$ °C unless otherwise noted

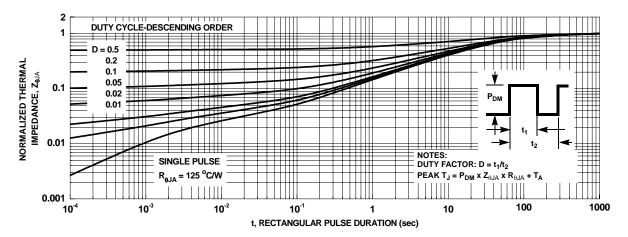


Figure 13. Transient Thermal Response Curve







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